

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria. Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE		FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/635,088	08/05/2003		Fred Matteson	4905-A-15	7232
33136	7590	07/09/2004		EXAMINER	
WILLIAM	C. CAHI	LL	NGO, NGAN V		
155 PARK ONE 2141 E. HIGHLAND AVENUE				ART UNIT	PAPER NUMBER
PHOENIX,			2814		

DATE MAILED: 07/09/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	A1:4/-)					
	Application No.	Applicant(s)					
Office Action Summary	10/635,088		MATTESON ET AL.				
Office Action Summary	Examin r	Art Unit	السه				
The MAN INC DATE of this communication	Ngan Ngo	2814	l r				
The MAILING DATE of this communication Period for Reply	appears on the cover sneet t	with the correspond nc ac	iaress				
A SHORTENED STATUTORY PERIOD FOR RETHE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CF after SIX (6) MONTHS from the mailing date of this communication. If the period for reply specified above is less than thirty (30) days, or if NO period for reply is specified above, the maximum statutory period for reply within the set or extended period for reply will, by some Any reply received by the Office later than three months after the rearned patent term adjustment. See 37 CFR 1.704(b).	ON. R 1.136(a). In no event, however, may and a reply within the statutory minimum of the riod will apply and will expire SIX (6) MO statute, cause the application to become	a reply be timely filed nirty (30) days will be considered time DNTHS from the mailing date of this of ABANDONED (35 U.S.C. § 133).	ly. communication.				
Status							
1) Responsive to communication(s) filed on _							
2a) ☐ This action is FINAL . 2b) ⊠	This action is non-final.						
,—	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims							
4) ☐ Claim(s) 1-15 is/are pending in the application 4a) Of the above claim(s) is/are with 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-14 is/are rejected. 7) ☐ Claim(s) 15 is/are objected to. 8) ☐ Claim(s) are subject to restriction are	ndrawn from consideration.						
Application Papers							
9) The specification is objected to by the Exar	miner.						
10)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.							
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
Replacement drawing sheet(s) including the control of the control	•		• •				
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for for a) All b) Some * c) None of: 1. Certified copies of the priority docum 2. Certified copies of the priority docum 3. Copies of the certified copies of the application from the International Bu * See the attached detailed Office action for a	nents have been received. nents have been received in priority documents have bee ureau (PCT Rule 17.2(a)).	Application No en received in this Nationa	l Stage				
Attachment(s) 1) ☑ Notice of References Cited (PTO-892) 2) ☑ Notice of Draftsperson's Patent Drawing Review (PTO-948	B) Paper N	v Summary (PTO-413) o(s)/Mail Date					
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SI Paper No(s)/Mail Date <u>0803</u> .	B/08) 5) Notice of 6) Other: _	f Informal Patent Application (PT	O-152) 				

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1 to 10 are rejected under 35 U.S.C. 102(b) as being anticipated by Ito et al.

Ito discloses a semiconductor die comprising a semiconductor substrate diffused with a first material (N-), a buried layer (206), an epitaxial layer (214), a first diffused region (204), a second diffused region (202), and a third diffused region (212).

In re claim 2, figure 27a clearly discloses the zener junction which is a reverse avalanche mode.

In re claim 3, the resistivity of the epitaxial layer is clearly higher than the resistivity of the buried layer.

In re claim 7, the electrostatic discharge circuit disclosed by Ito is clearly a transient voltage suppression device.

In re claim 10, Ito clearly show the first and second external electrical contact on the second diffused region (202) and the third diffused region (212).

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Page 3

Claims 11-14 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lie et al in view of Ito et al.

Lie et al disclose a flip chip comprising a transient voltage suppression device.

Note figure 4 of Lie. However Lie does not disclose a particular transient voltage suppression device as claimed by Applicants. Ito disclose a semiconductor die comprising a substrate, a buried layer, an epitaxial layer, a first diffused region, a second diffused region, and a third diffused region to form a transient voltage suppression device. Therefore, it would have been obvious to one of ordinary skill in the art to form the transient voltage suppression device as taught by Ito in a flip chip taught by Lie in order to provide a package for the transient voltage suppression device.

Claim 15 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The other references are cited to show other structures pertinent to Applicants' disclosure.

Any inquiry concerning this communication should be directed to Examiner Ngan Ngo at telephone number (571) 272-1711. The fax number for the Art unit is (703) 308-7722.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the Group receptionist whose telephone number is (703) 308-0956.

Ngan Ngo

July 7, 2004

Page 4

Ngan Van Ngo Primary Examiner